Supplementary Information

Efficient interfacial interaction for improving mechanical properties of

polydimethylsiloxane nanocomposites filled with low content of graphene oxide

nanoribbons

Neng-Jian Huang,^a Jing Zang,^a Guo-Dong Zhang,^{a*} Li-Zhi Guan,^a Shi-Neng Li,^{ab} Li Zhao,^a Long-Cheng

Tang ^{a*}

^a Key Laboratory of Organosilicon Chemistry and Material Technology of Ministry of Education,

College of Material, Chemistry and Chemical Engineering, Hangzhou Normal University, Hangzhou

311121, PR China

^b Institute for Advanced Ceramics, State Key Laboratory of Urban Water Resource and

Environment, Harbin Institute of Technology, Harbin 150001, PR China

*E-mails: zhangguodong@hznu.edu.cn (G.D. Zhang), lctang@hznu.edu.cn (L.C. Tang)

Fig. S1 Schematic of the fabrication process for H-t-PDMS/GONR composites (The black tensile and tear samples were prepared and shown in figure).



Fig. S2 The dispersion stability of various carbon nanofillers (CNT, f-CNT and GONR) in aqueous solution.



17 days later



Fig. S3 TEM images of (a, b) f-CNT at different magnification.



Fig. S4 SEM images of tensile fracture surface of pure H-t-PDMS at different magnification.



Fig. S5 Typical tensile stress-strain curves of pure H-t-PDMS and H-t-PDMS composites filled with 0.5 wt% CNT, f-CNT and GONR.



Fig. S6 SEM images of tensile fracture surface at different magnification of H-t-PDMS composites filled with 0.5 wt% (a, b) CNT and (c, d) f-CNT. (The black arrows indicate the nanotubes in the polymer matrix.)



Table S1. Tensile strength, Young's modulus and elongation at break of pure H-t-PDMS and H-t-PDMS/GONR composites filled with different GONR contents.

Sample	Ε	σ_b	ε
Code	[MPa]	[MPa]	[%]
Pure H-t-PDMS	0.98±0.06	0.350±0.015	90.28±13.77
H-t-PDMS/GONR-0.05	1.22±0.10	0.413±0.025	96.80±11.46
H-t-PDMS/GONR-0.1	1.25±0.07	0.504±0.053	127.19±15.38
H-t-PDMS/GONR-0.3	1.36±0.05	0.615±0.046	135.07±11.42
H-t-PDMS/GONR-0.5	1.93±0.14	0.902±0.050	179.42±22.43
H-t-PDMS/GONR-0.7	1.56±0.09	0.744±0.047	153.63±18.69
H-t-PDMS/GONR-1.0	1.24±0.12	0.545±0.056	116.94±20.75